MRPC simulation

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MRPC simulation

- Standalone digitization software developed for MRPC
- Based on the pCDR design
 - 10 gas gaps with a width of 0.25mm
 - Resistive plate with a width of 0.7 mm
 - gas mixture: $C_2F_4H_2$ (90%) : SF_6 (5%) : iso- C_4H_{10} (5%)
 - Strip readout at both ends

Basic scheme



- Avalanche simulation based on the 1D model and the central limit theorem (Nucl. Instrum. Meth. A 500 (1-3) (2003) 144)
- Avalanche development can be characterized by two coefficient: Townsend coefficient (α) and attachment coefficient (η)
- P(n,x): probability for an avalanche started with a single electron to contain n electrons after distance x
- General solution is given as:

$$P(n,x) = \begin{cases} k \frac{n(x)-1}{\overline{n}(x)-k}, & (n=0) & \overline{n}(x) = e^{(\alpha-\eta)x} \\ (average number of electrons) \\ \overline{n}(x) \left(\frac{1-k}{\overline{n}(x)-k}\right)^2 \left(\frac{\overline{n}(x)-1}{\overline{n}(x)-k}\right)^{n-1}, (n>0) & k = \frac{\eta}{\alpha} \end{cases}$$

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• Single gap avalanche simulation





- The positions of primary electrons are given by GEANT4 hit and Poisson distribution
- For each step, calculate the number of electrons with a probability for ionization/attachment (switches to the effective calculation from Gaussian distribution if N_e > 200)
- Simplified space charge effect: Number of electrons limited to 1.5e7



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Strip mapping



- # supermodules: 50
 - each module has 7.2 of azimuthal angle coverage
- # strips: 33
 - Strip width: 25mm, gap: 3mm
- Minimum radial position of the first trip in order to set it to 130 mm:
 - R_{bottom}: 1033.15 mm (at least)

Virtual front plane



- Line equation: hit position at the virtual front plane and average position inside the gap
- X, Y positions of primary ions

Assume modules are overlapping to reduce blind region

Slewing correction



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Single particle simulation

- K[±], π[±], p, e
- Single particle generation at the target position (z = -3500 mm)
- Initial momentum range of [0, 10] GeV, flat p
- Select only prompt hadrons/electrons by checking the track information



TOF PID



 $\Delta t = time_measured (t_{Ref} + t_{Leading}) - time_expected$

Performance in simulation

- Detection efficiency: (#MRPC signal)/(#VFP track)
- Average efficiency > ~98%



p/K separation



Summary and outlook

- Initial study with the MRPC simulation
- Further implementation of other uncertainty sources for more realistic time resolution
- Finishing up the tech note
- First version of codes on github:
 - <u>https://github.com/sanghwapark/SolMRPC</u>

(instruction will be up soon)

Backup



E = 108 kV/cm

Townsend coefficient (α) = 129/mm Attachment coefficient (η) = 5.435/ mm

Drift velocity = 0.201 mm/ns



- Used the same random seed for the comparison.
- Only minor difference in the avalanche size between the general solution and SoLID Collaboration Meeting the effective model.

Module design



- 3.6 degree is ~ 6.28e-2 rad
- Minimum radial position of the first trip in order to set it to 130 mm:

- R_{bottom}: 1033.15 mm (at least)

- 11th strip is supposed to have a strip length of 170 mm according to the pCDR
- With this initial condition, 11th strip would be located at R_{bottom} of 1033.15 + 250 + 30 ≅ 1313
- To follow the pCDR design: 25 mm strip width, 3mm interval → the length of 11th strip would be limited to 165.2 mm instead of 170 mm.
 - In order to have the 11th strip with a length of 170 mm, the bottom of the first strip should be located at least at 1071 mm from the center.
- At R = 960 mm, the maximum strip length is ~ 120.8 mm
- The bottom/top edge design would depend on physias?Collaboration Meeting

3.6°

96 cm

Calibration





Slewing correction for MC



 Further iteration doesn't make much difference

Slewing correction



BeamOnTarget



Slewing correction

